



Vincotech

flowRPI 1		650 V / 30 A
Features		flow 1 12 mm housing
<ul style="list-style-type: none">• High integration level of Rectifier, PFC and Inverter• Interleaved PFC with high efficiency, fast IGBT H5 + ultra-fast Si Diode• High efficiency H-Bridge inverter with fast IGBT H5• Integrated Temperature Sensor and Capacitor		
Target applications		Schematic
<ul style="list-style-type: none">• Charging Stations• Power Supply• Welding & Cutting		
Types		
<ul style="list-style-type: none">• 10-FY07ZAA030SM-L513B28		

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Rectifier Diode				
Peak repetitive reverse voltage	V_{RRM}		1600	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	46	A
Surge (non-repetitive) forward current	I_{FSM}	50 Hz Single Half Sine Wave $t_p = 10 \text{ ms}$	270	A
Surge current capability	I^2t		370	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	56	W
Maximum junction temperature	T_{jmax}		150	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
PFC Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	25	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	60	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	51	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
PFC Diode				
Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
H-Bridge Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	31	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	90	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	60	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
H-Bridge Diode				
Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	28	A
Repetitive peak forward current	I_{FRM}		40	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	51	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



10-FY07ZAA030SM-L513B28

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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Current Transformer Protection Diode				
Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	14	A
Repetitive peak forward current	I_{FRM}		20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	33	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

PFC Sw. Protection Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	14	A
Repetitive peak forward current	I_{FRM}		20	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	33	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Capacitor (DC)

Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55...+125	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{op}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance				7,58	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit		
			V_{GE} [V]	V_{CE} [V]	I_c [A]	V_{GS} [V]	V_{DS} [V]	I_D [A]	T_j [°C]	I_F [A]	Min	Typ	Max

Rectifier Diode

Static

Forward voltage	V_F				35	25 125		1,17 1,13			V
Reverse leakage current	I_R			1600		25			50		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,25			K/W
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10-FY07ZAA030SM-L513B28

datasheet

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

PFC Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0002	25	3,3	4	4,7	V
Collector-emitter saturation voltage	V_{CESat}		15		20	25 125 150		1,60 1,75 1,79	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25			40	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25	25		1200		pF
Output capacitance	C_{oes}							30		
Reverse transfer capacitance	C_{res}							5,2		
Gate charge	Q_g		15	520	20	25		48		

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						1,88		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 16 \Omega$ $R_{goff} = 16 \Omega$	0 / 15	400	20	25		17		ns
Rise time	t_r					125		8		
Turn-off delay time	$t_{d(off)}$					150		7		
Fall time	t_f	$Q_{fFWD} = 0,3 \mu\text{C}$ $Q_{fFWD} = 0,7 \mu\text{C}$ $Q_{fFWD} = 0,8 \mu\text{C}$	25	125	150	100				mWs
Turn-on energy (per pulse)	E_{on}					123				
Turn-off energy (per pulse)	E_{off}					121				
						25		8		
						125		8		
						150		10		
						25		0,321		
						125		0,443		
						150		0,438		
						25		0,071		
						125		0,116		
						150		0,162		



10-FY07ZAA030SM-L513B28

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

PFC Diode

Static

Forward voltage	V_F				20	25 125 150		2,16 1,93 1,88	2,6		V
Reverse leakage current	I_R			650		25			10		μA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						2,52		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 2752 \text{ A}/\mu\text{s}$ $di/dt = 2749 \text{ A}/\mu\text{s}$ $di/dt = 2605 \text{ A}/\mu\text{s}$	0 / 15	400	20	25		15			A
Reverse recovery time	t_{rr}					125		18			
Recovered charge	Q_r					150		18			
Recovered charge	Q_r	$di/dt = 2752 \text{ A}/\mu\text{s}$ $di/dt = 2749 \text{ A}/\mu\text{s}$ $di/dt = 2605 \text{ A}/\mu\text{s}$	0 / 15	400	20	25		20			ns
Reverse recovered energy	E_{rec}					125		107			
Reverse recovered energy	E_{rec}					150		123			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$	$di/dt = 2752 \text{ A}/\mu\text{s}$ $di/dt = 2749 \text{ A}/\mu\text{s}$ $di/dt = 2605 \text{ A}/\mu\text{s}$	0 / 15	400	20	25		0,303			μC
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		0,675			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		0,808			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$	$di/dt = 2752 \text{ A}/\mu\text{s}$ $di/dt = 2749 \text{ A}/\mu\text{s}$ $di/dt = 2605 \text{ A}/\mu\text{s}$	0 / 15	400	20	25		0,061			mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		0,137			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		0,179			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$	$di/dt = 2752 \text{ A}/\mu\text{s}$ $di/dt = 2749 \text{ A}/\mu\text{s}$ $di/dt = 2605 \text{ A}/\mu\text{s}$	0 / 15	400	20	25		1718			$\text{A}/\mu\text{s}$
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		1004			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		753			



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V]	V_{CE} [V]	V_{DS} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max	
		V_{GS} [V]	V_F [V]	I_F [A]							

H-Bridge Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0003	25	3,3	4	4,7	V
Collector-emitter saturation voltage	V_{CESat}		15		30	25 125 150		1,67 1,80 1,84	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25			40	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25	25		2100		pF
Reverse transfer capacitance	C_{res}							7,7		
Gate charge	Q_g		15	520	30	25		70		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,57		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 16 \Omega$ $R_{goff} = 16 \Omega$	-5 / 15	350	30	25		35		ns
Rise time	t_r					125		34		
						150		37		
Turn-off delay time	$t_{d(off)}$					25		10		
						125		10		
Fall time	t_f					150		10		
Turn-on energy (per pulse)	E_{on}	$Q_{rFWD} = 0,8 \mu\text{C}$ $Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 1,8 \mu\text{C}$				25		87		mWs
						125		101		
						150		105		
Turn-off energy (per pulse)	E_{off}					25		8		
						125		9		
						150		10		
						25		0,632		
						125		0,786		
						150		0,803		
						25		0,111		
						125		0,166		
						150		0,191		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

H-Bridge Diode

Static

Forward voltage	V_F				20	25 125 150		1,56 1,51 1,51	1,92		V
Reverse leakage current	I_R			650		25			1,28		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,88		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 2702 \text{ A/}\mu\text{s}$ $di/dt = 2470 \text{ A/us}$ $di/dt = 2358 \text{ A/}\mu\text{s}$	-5 / 15	350	30	25		14			A
Reverse recovery time	t_{rr}					125		20			
						150		23			
Recovered charge	Q_r					25		105			ns
Recovered charge	Q_r					125		126			
Recovered charge	Q_r					150		137			
Reverse recovered energy	E_{rec}	$di/dt = 2702 \text{ A/}\mu\text{s}$ $di/dt = 2470 \text{ A/us}$ $di/dt = 2358 \text{ A/}\mu\text{s}$	-5 / 15	350	30	25		0,801			µC
Reverse recovered energy	E_{rec}					125		1,539			
Reverse recovered energy	E_{rec}					150		1,781			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		0,139			mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		0,289			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		0,352			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		78			A/µs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		162			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		149			

Current Transformer Protection Diode

Static

Forward voltage	V_F				10	25 125		1,67 1,56	1,87		V
Reverse leakage current	I_R			650		25			0,14		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						2,87		K/W
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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

PFC Sw. Protection Diode

Static

Forward voltage	V_F				10	25 125		1,67 1,56	1,87	V
Reverse leakage current	I_R			650		25			0,14	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						2,87		K/W
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Capacitor (DC)

Capacitance	C							100		nF
Tolerance							-10		+10	%
Dissipation factor		$f = 1 \text{ kHz}$				25			2,5	%

Thermistor

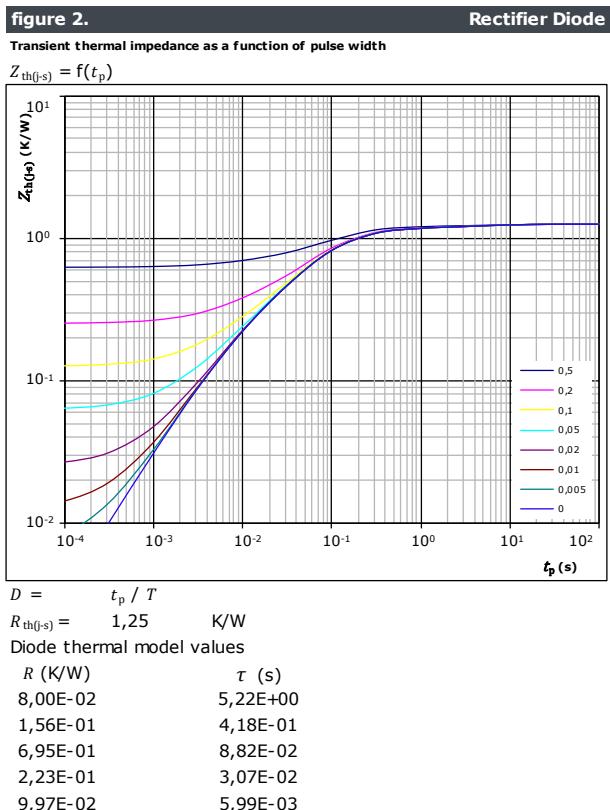
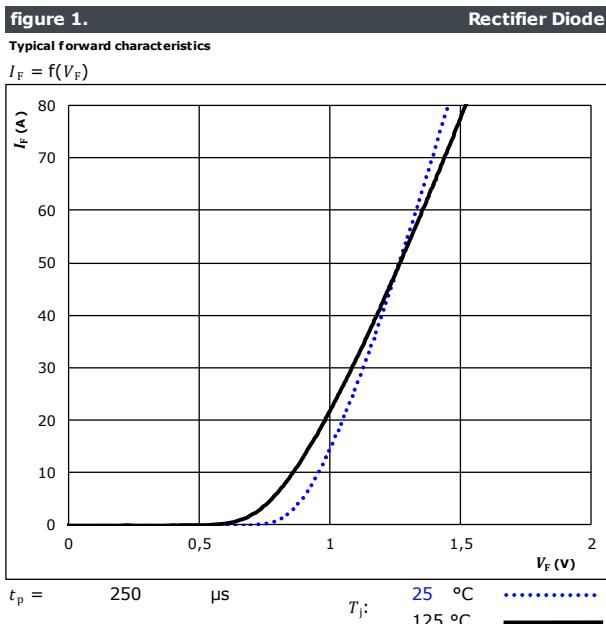
Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P				25		5			mW
Power dissipation constant					25		1,5			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %			25		3962			K
B-value	$B_{(25/100)}$	Tol. ±1 %			25		4000			K
Vincotech NTC Reference								I		



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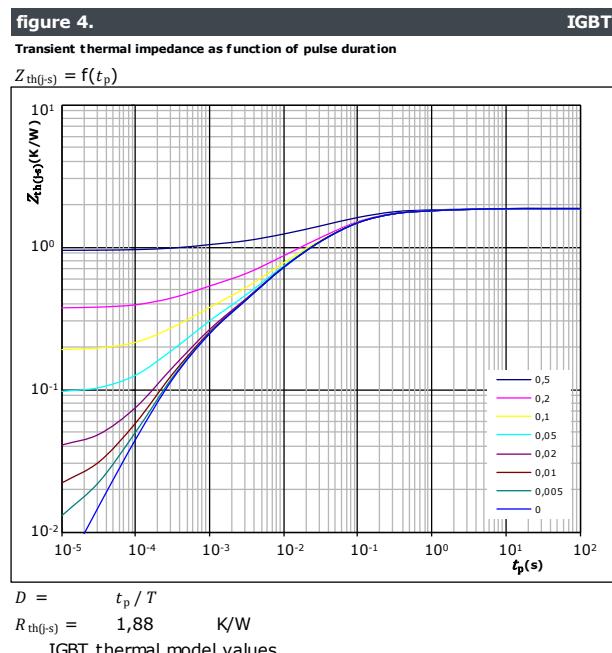
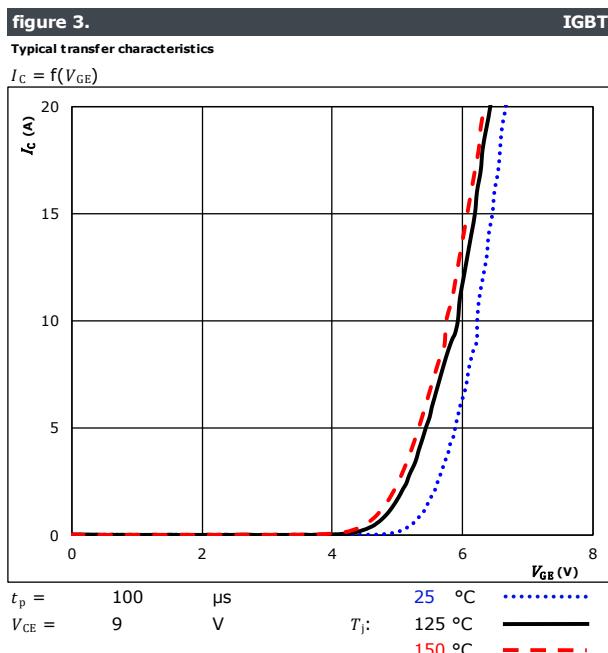
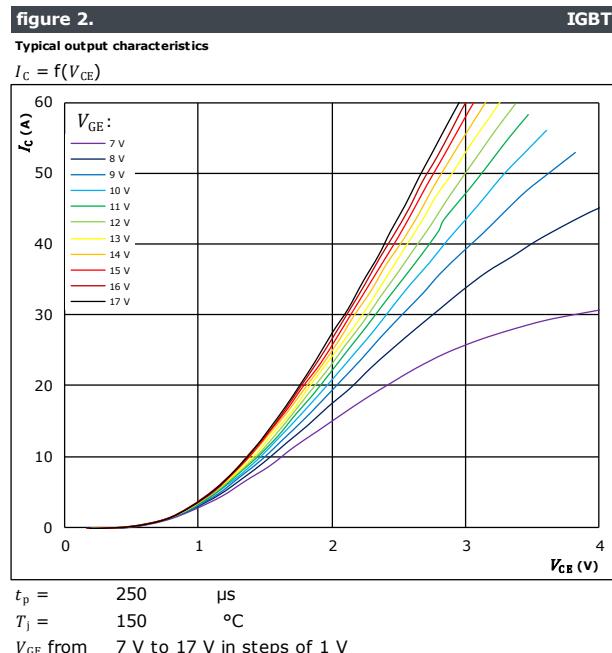
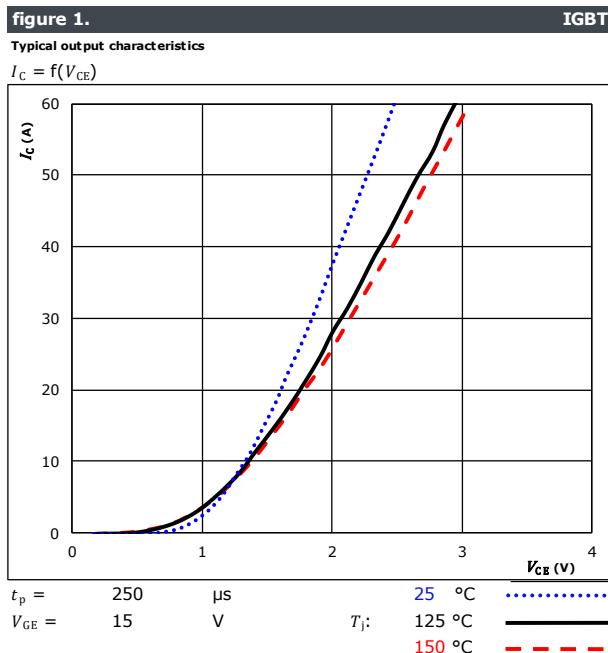
Rectifier Diode Characteristics





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PFC Switch Characteristics

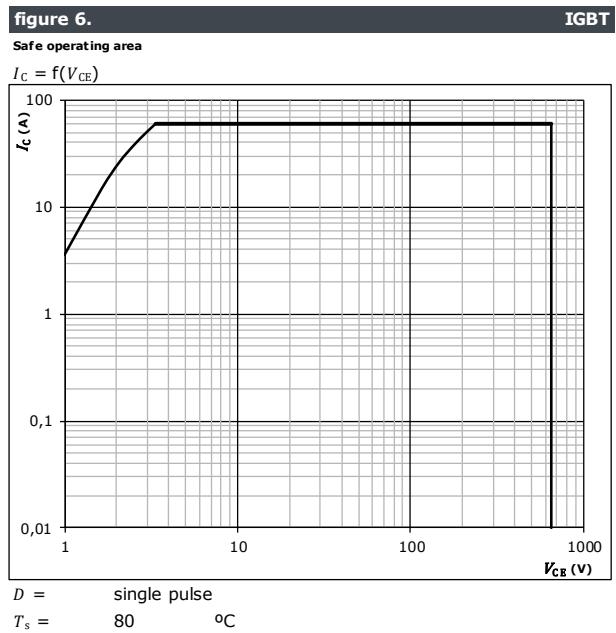
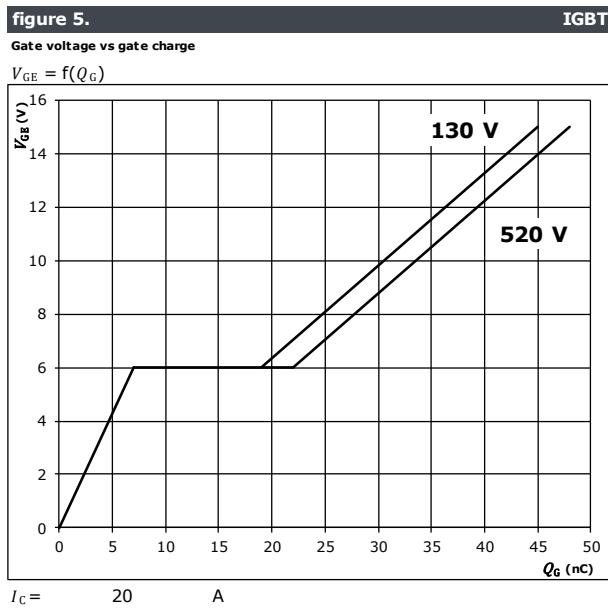




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PFC Switch Characteristics

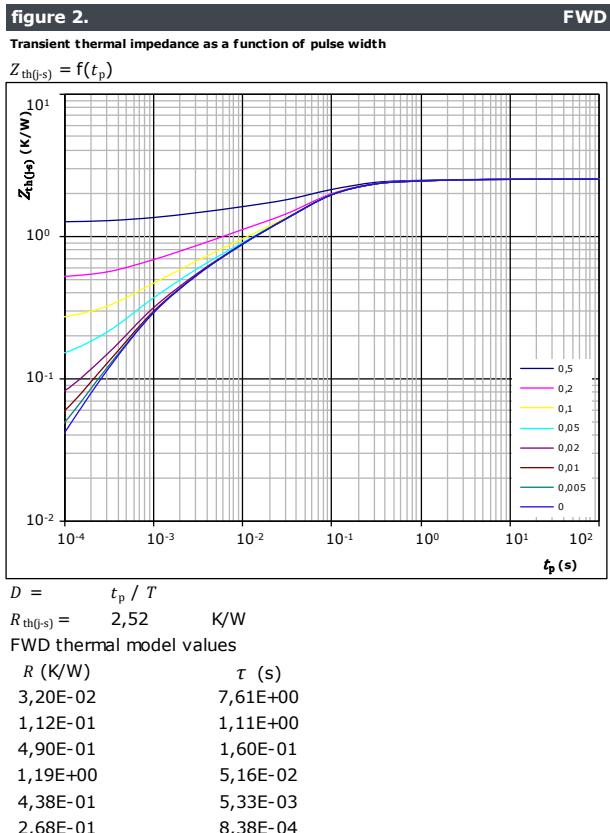
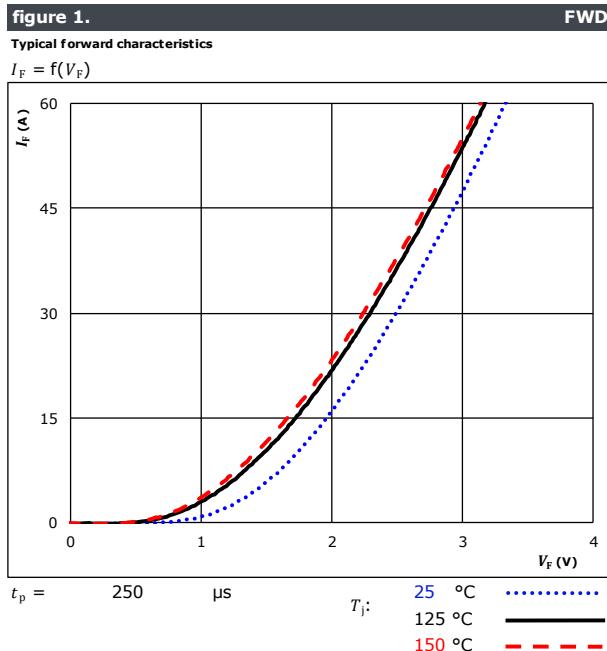




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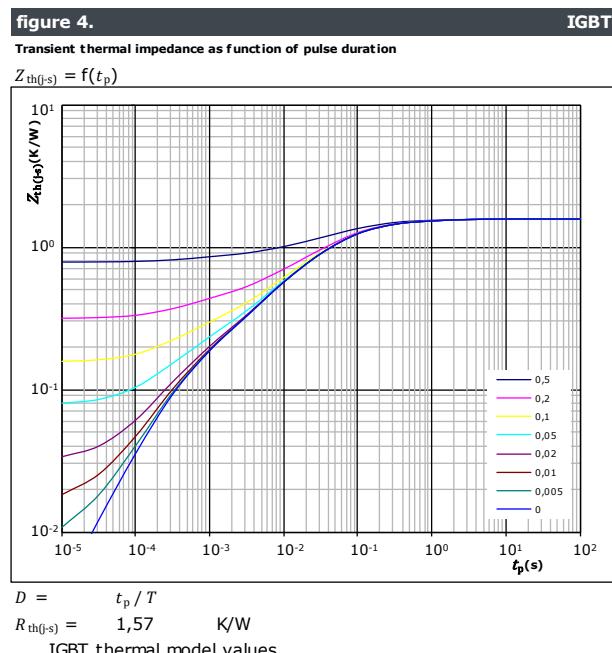
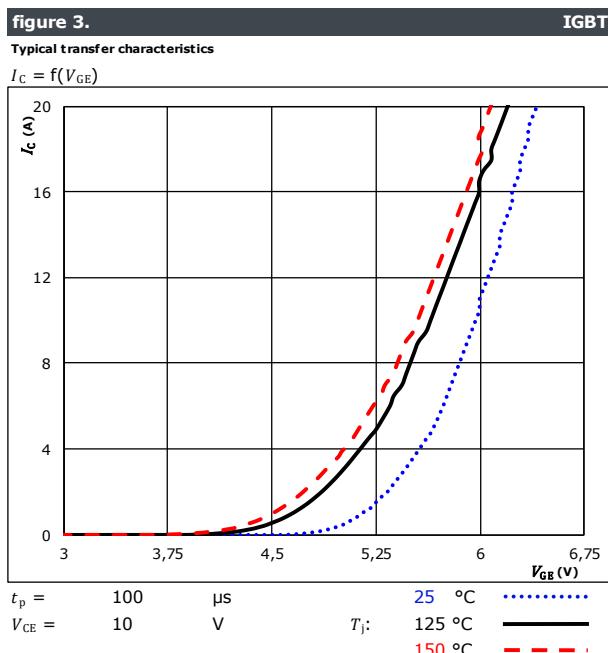
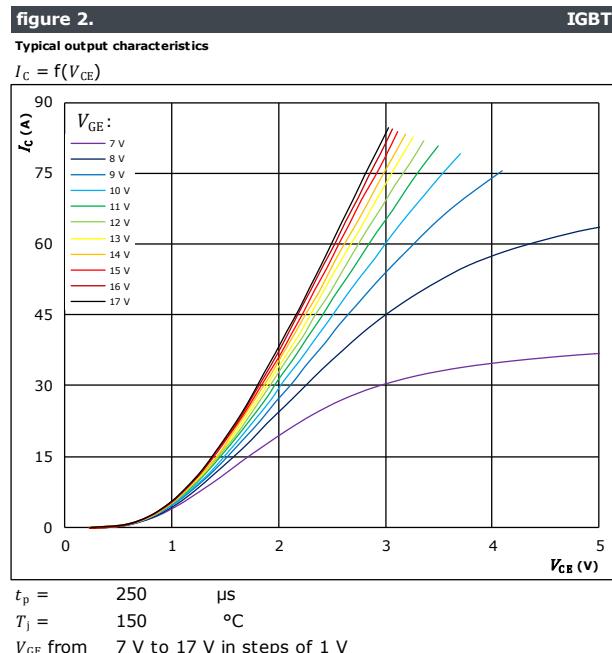
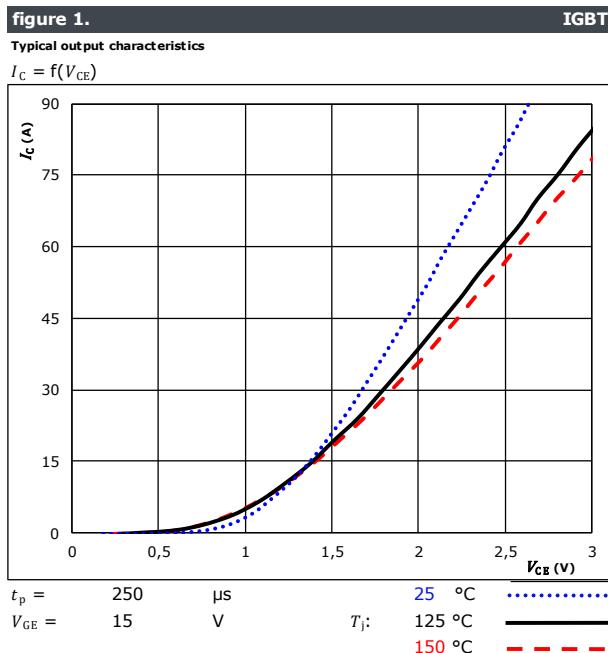
PFC Diode Characteristics





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H-Bridge Switch Characteristics





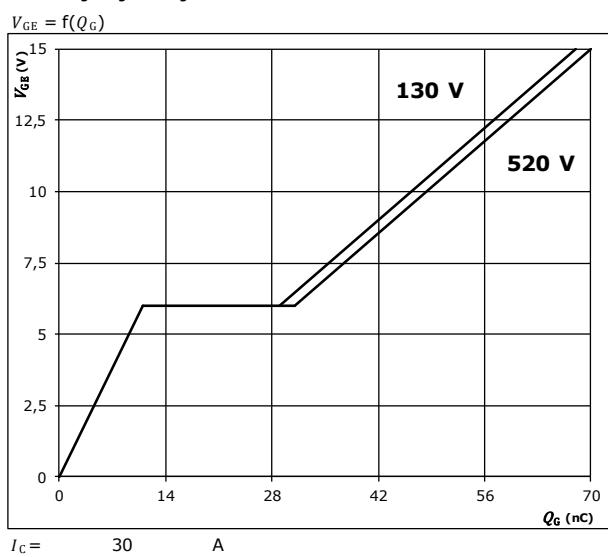
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H-Bridge Switch Characteristics

figure 5.

Gate voltage vs gate charge

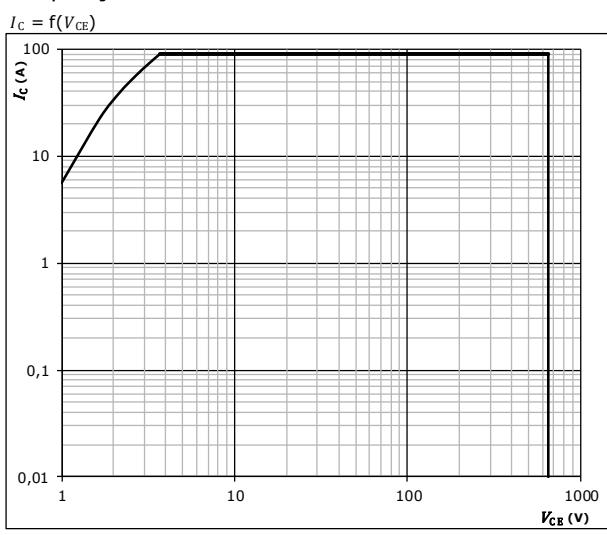


$I_C = \dots$

A

figure 6.

Safe operating area



$D = \text{single pulse}$

$T_s = 80 \text{ } ^\circ\text{C}$

$V_{GE} = \pm 15 \text{ V}$

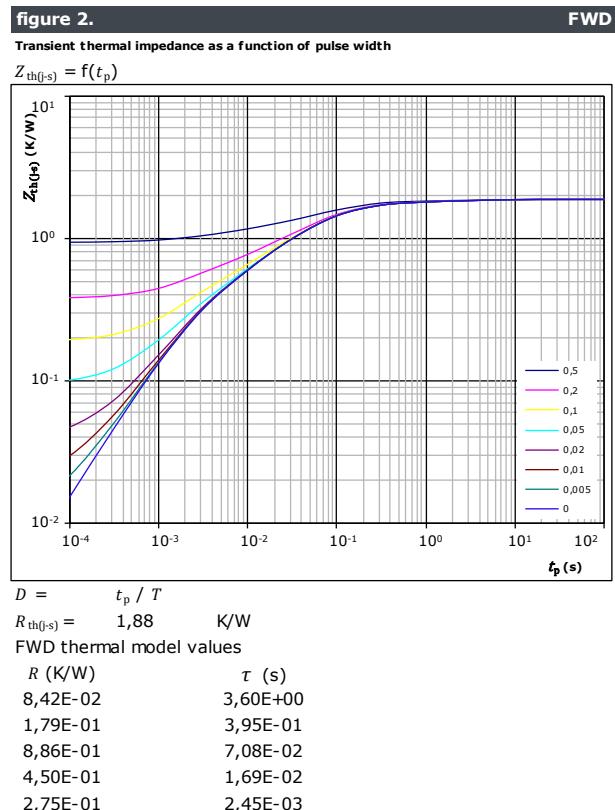
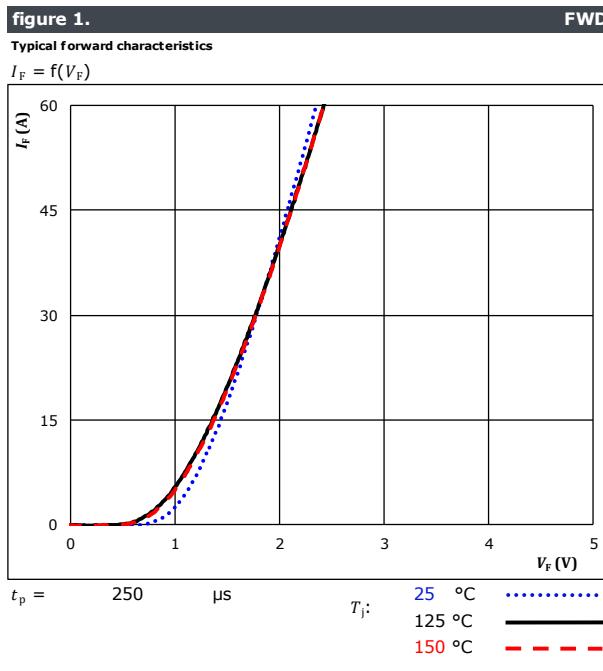
$T_j = T_{jmax}$



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H-Bridge Diode Characteristics

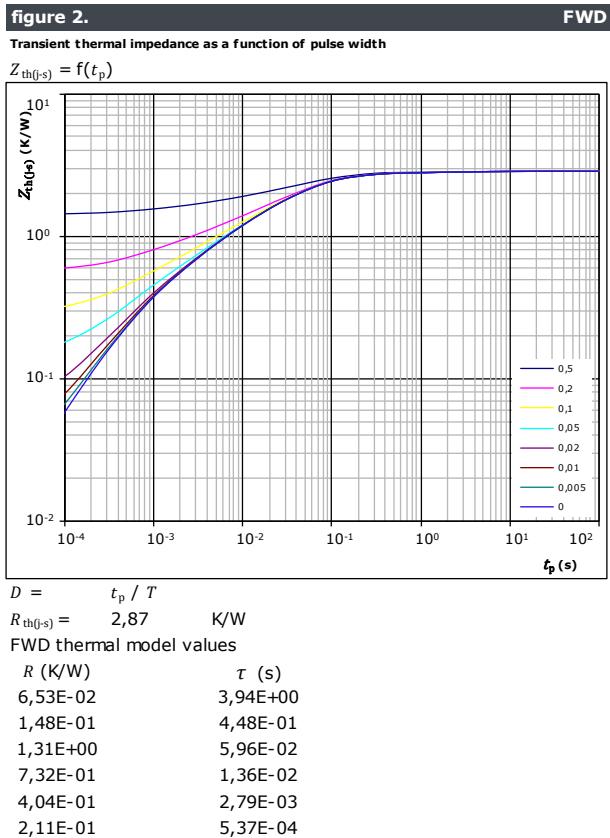
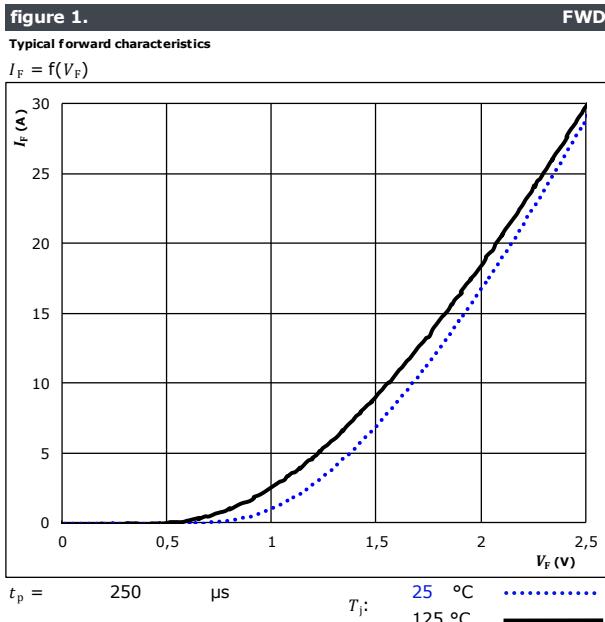




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Current Transformer Protection Diode Characteristics

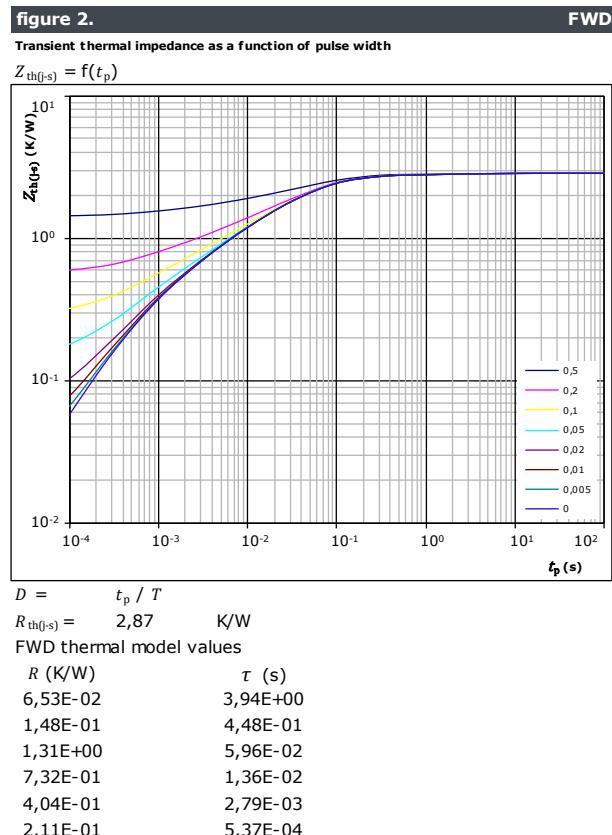
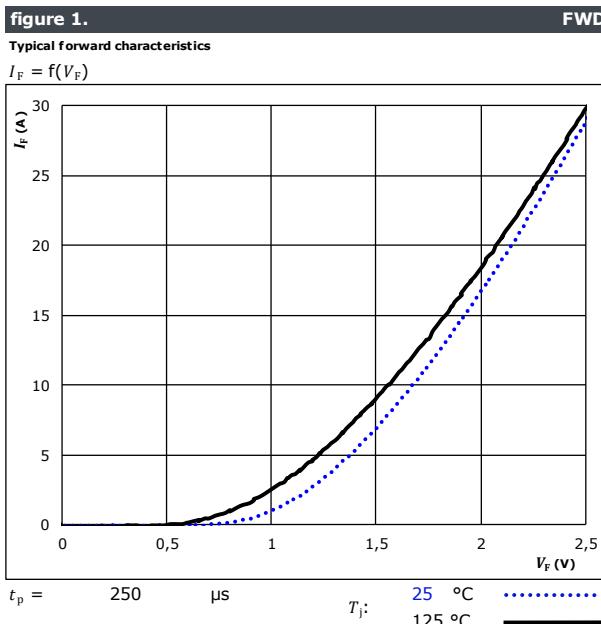




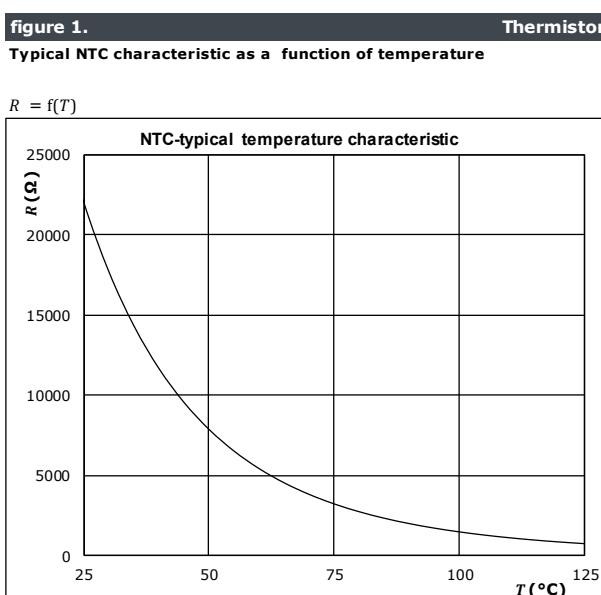
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PFC Sw. Protection Diode Characteristics



Thermistor Characteristics

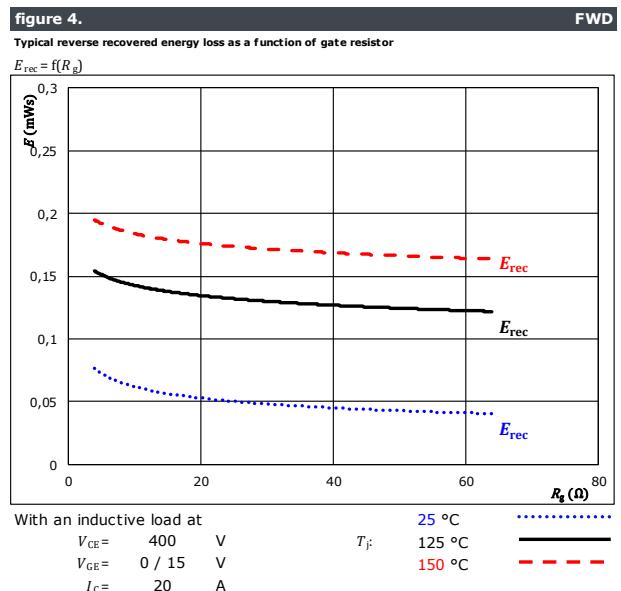
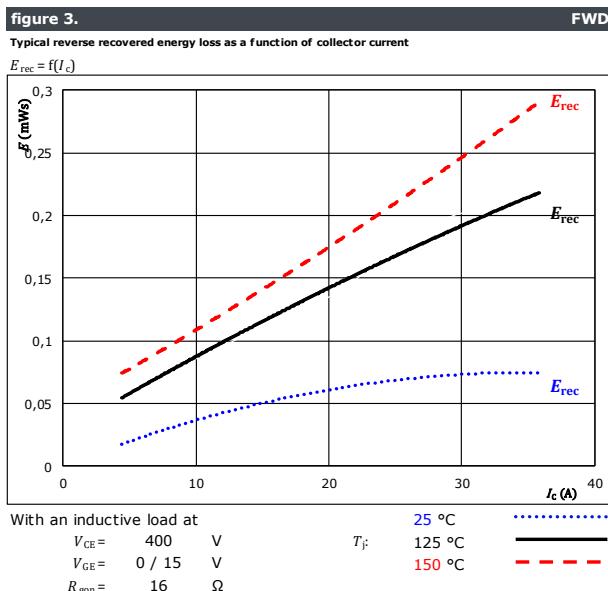
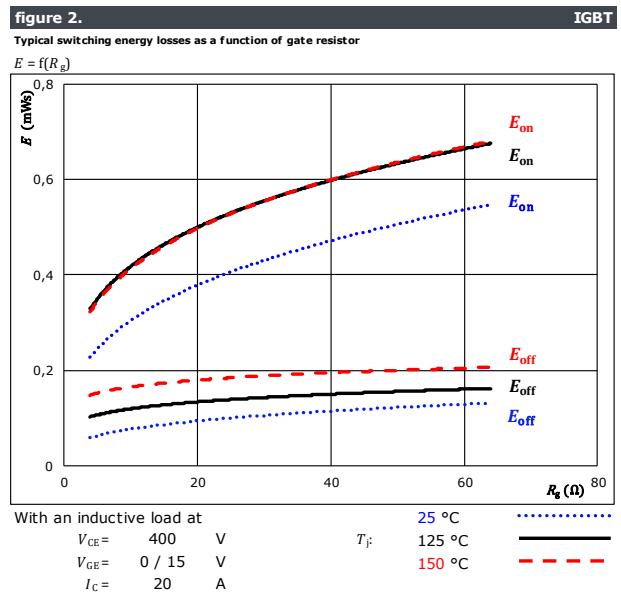
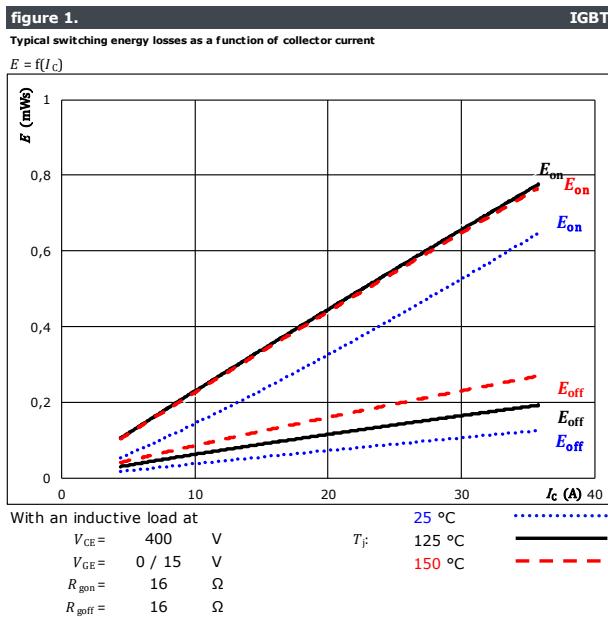




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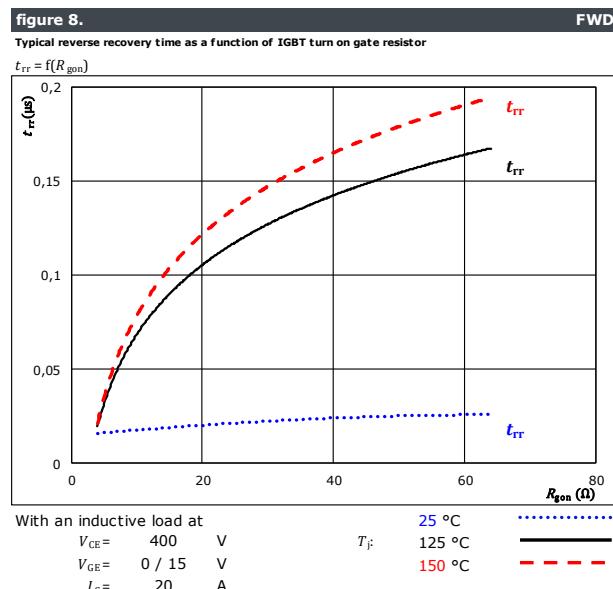
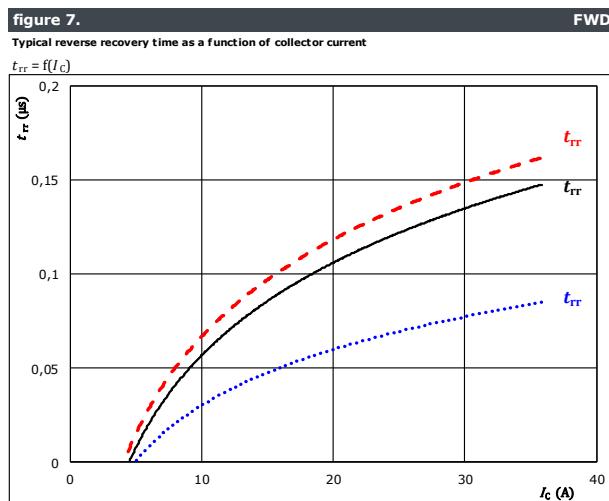
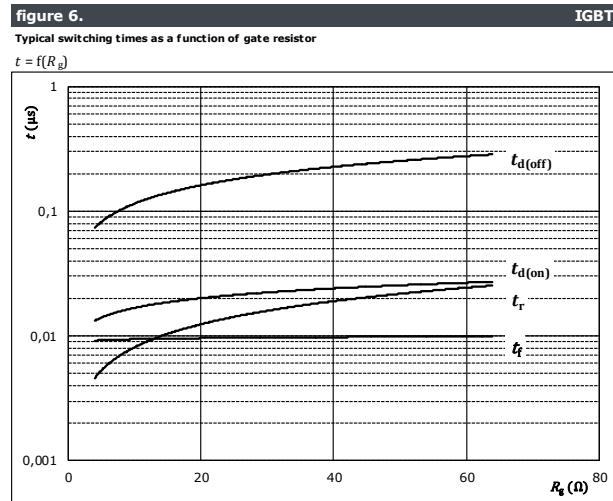
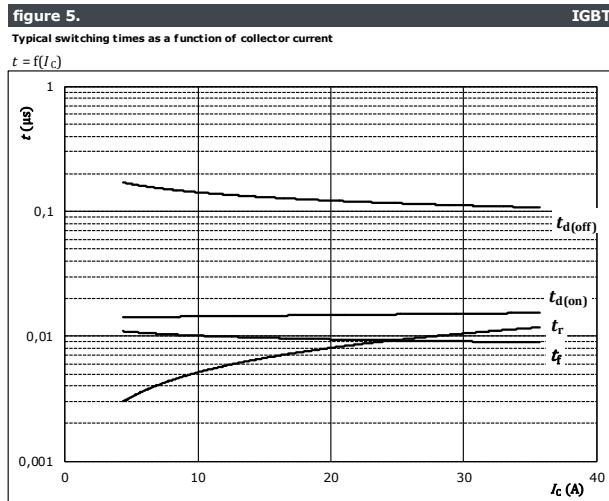
PFC Switching Characteristics





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PFC Switching Characteristics

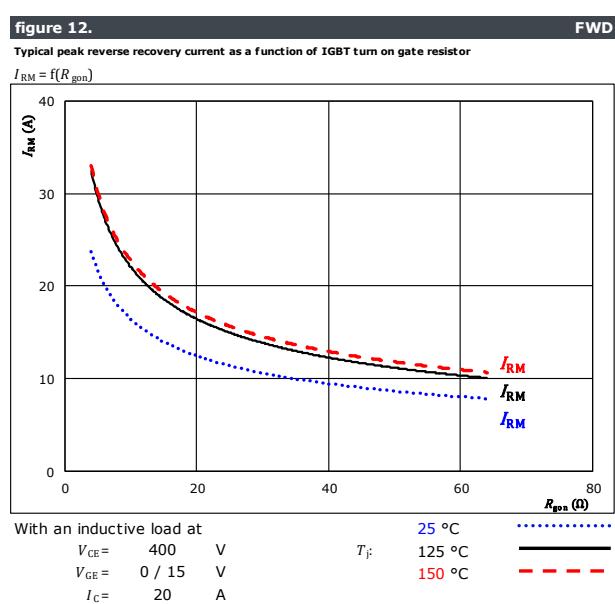
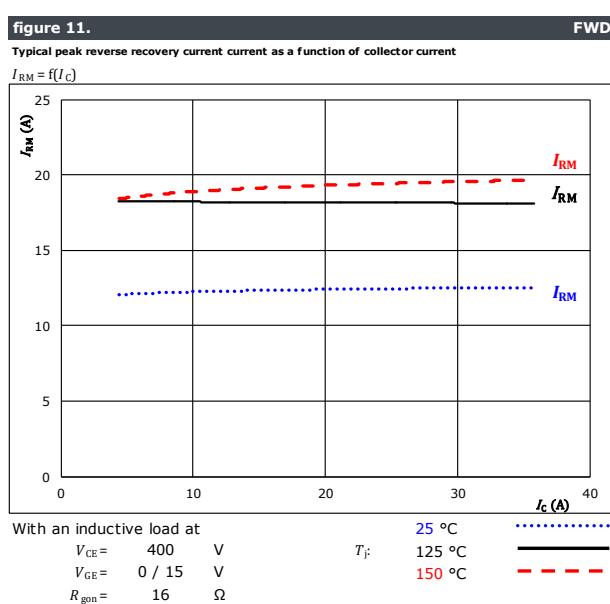
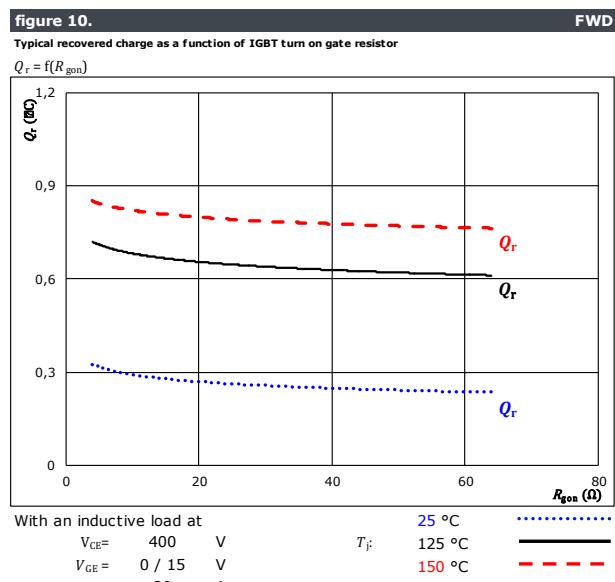
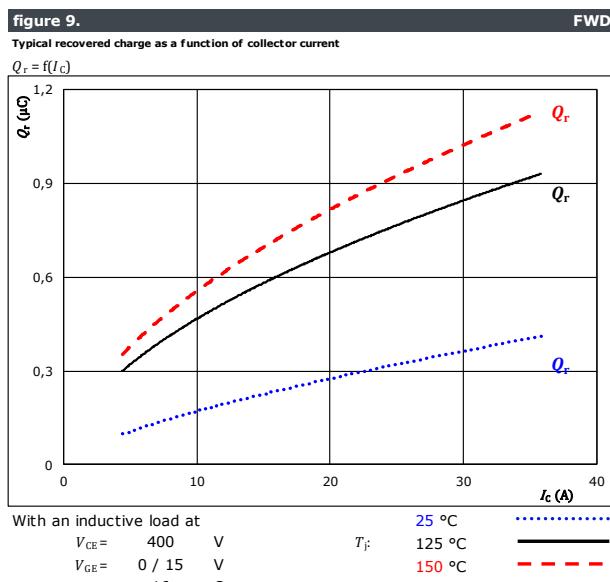




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datasheet

PFC Switching Characteristics





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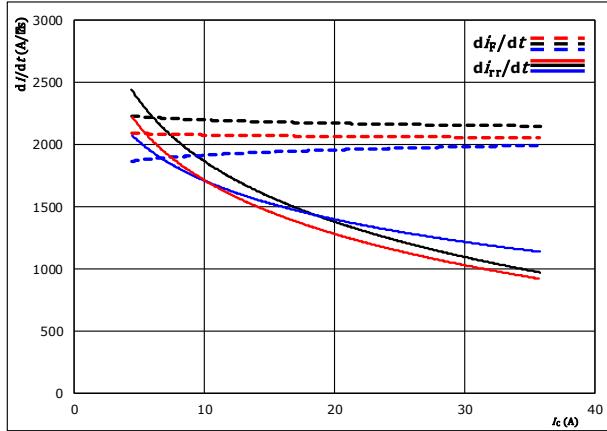
10-FY07ZAA030SM-L513B28
datasheet

PFC Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$$di_F/dt, di_{rr}/dt = f(I_C)$$



With an inductive load at

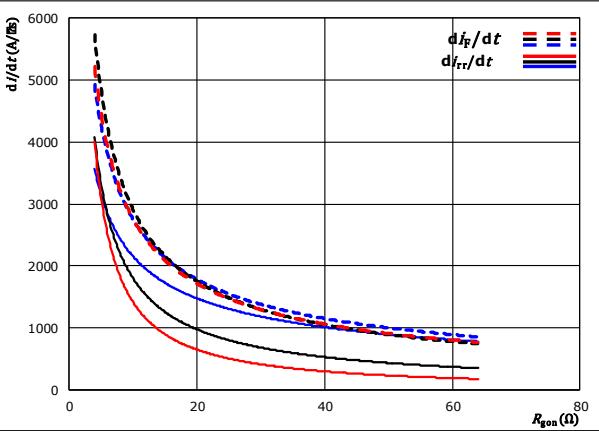
$$\begin{aligned} V_{CE} &= 400 \quad \text{V} & T_J &= 25^\circ\text{C} \\ V_{GE} &= 0 / 15 \quad \text{V} & & \\ R_{gon} &= 16 \quad \Omega & & \end{aligned}$$

FWD

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$$di_F/dt, di_{rr}/dt = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \quad \text{V} & T_J &= 25^\circ\text{C} \\ V_{GE} &= 0 / 15 \quad \text{V} & & \\ I_C &= 20 \quad \text{A} & & \end{aligned}$$

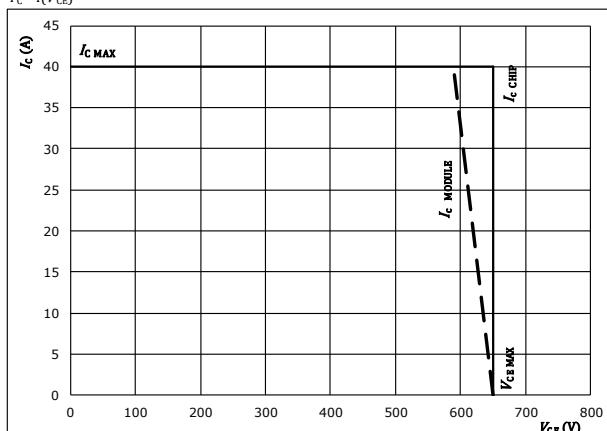
FWD

figure 15.

IGBT

Reverse bias safe operating area

$$I_C = f(V_{CE})$$



At

$$\begin{aligned} T_J &= 150 \quad \text{°C} \\ R_{gon} &= 16 \quad \Omega \\ R_{goff} &= 16 \quad \Omega \end{aligned}$$



Vincotech

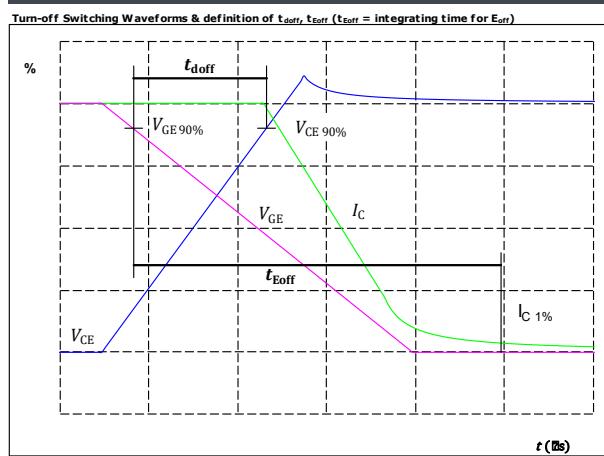
PFC Switching Definitions

General conditions

T_j	=	150 °C
R_{gon}	=	16 Ω
R_{goff}	=	16 Ω

figure 1.

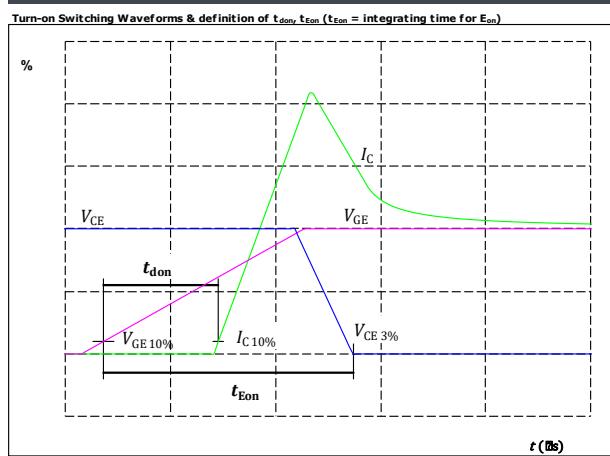
IGBT



$V_{GE\ (0\%)} =$	0	V
$V_{GE\ (100\%)} =$	15	V
$V_C\ (100\%) =$	400	V
$I_C\ (100\%) =$	20	A
$t_{doff} =$	121	ns

figure 2.

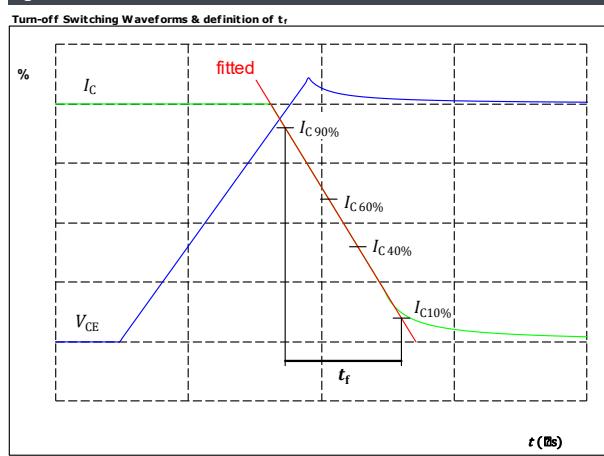
IGBT



$V_{GE\ (0\%)} =$	0	V
$V_{GE\ (100\%)} =$	15	V
$V_C\ (100\%) =$	400	V
$I_C\ (100\%) =$	20	A
$t_{don} =$	14	ns

figure 3.

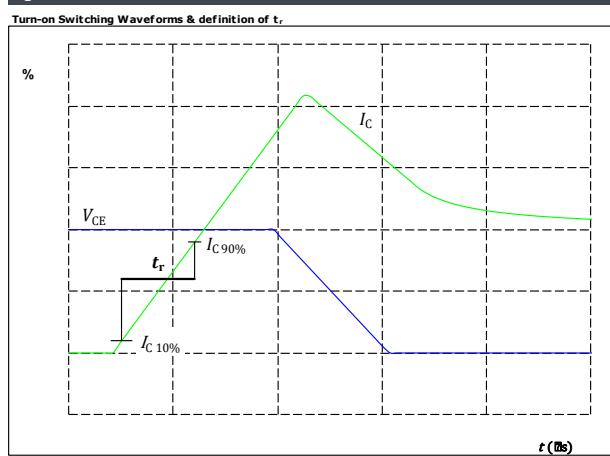
IGBT



$V_C\ (100\%) =$	400	V
$I_C\ (100\%) =$	20	A
$t_f =$	10	ns

figure 4.

IGBT



$V_C\ (100\%) =$	400	V
$I_C\ (100\%) =$	20	A
$t_r =$	8	ns



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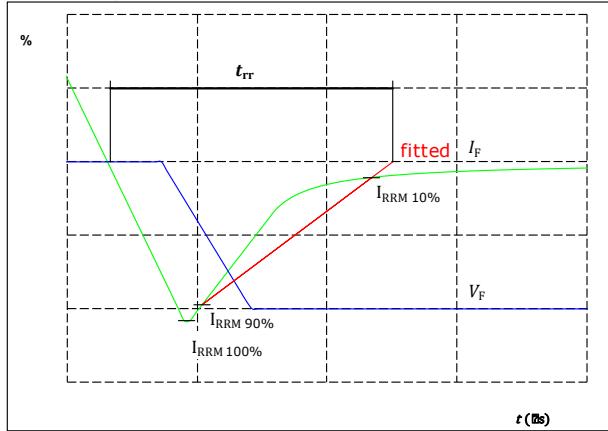
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datasheet

PFC Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

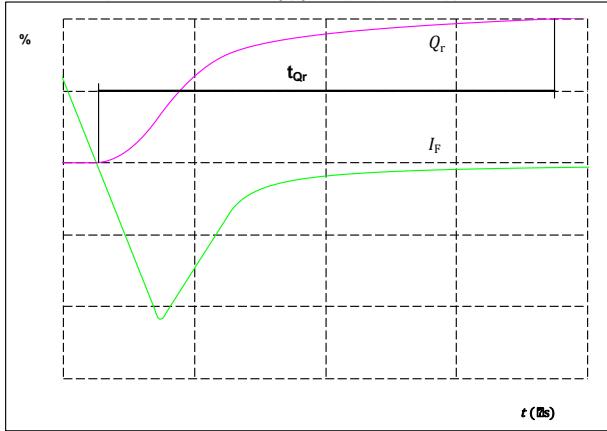


$V_F(100\%) =$ 400 V
 $I_F(100\%) =$ 20 A
 $I_{RRM}(100\%) =$ 18 A
 $t_{rr} =$ 123 ns

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)



$I_F(100\%) =$ 20 A
 $Q_r(100\%) =$ 1 μ C



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H-Bridge Switching Characteristics

figure 1.

Typical switching energy losses as a function of collector current

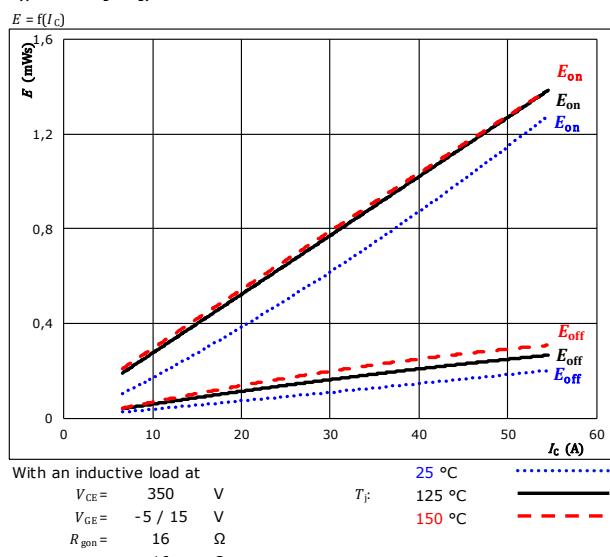


figure 2.

Typical switching energy losses as a function of gate resistor

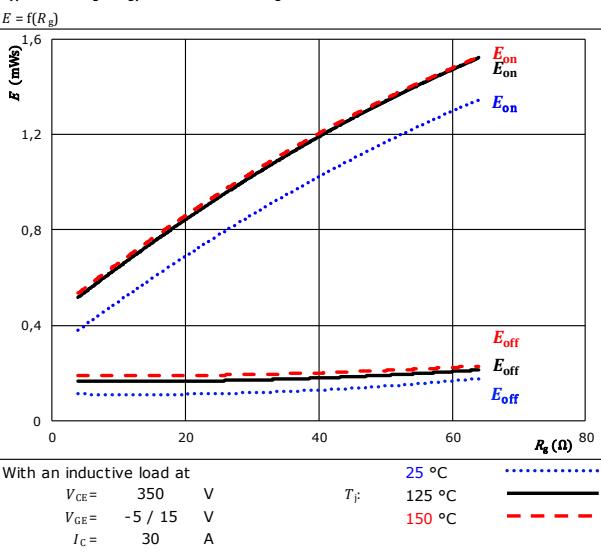


figure 3.

Typical reverse recovered energy loss as a function of collector current

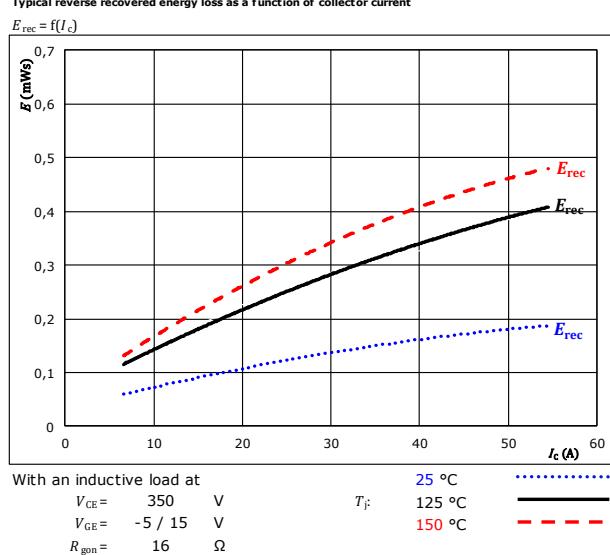
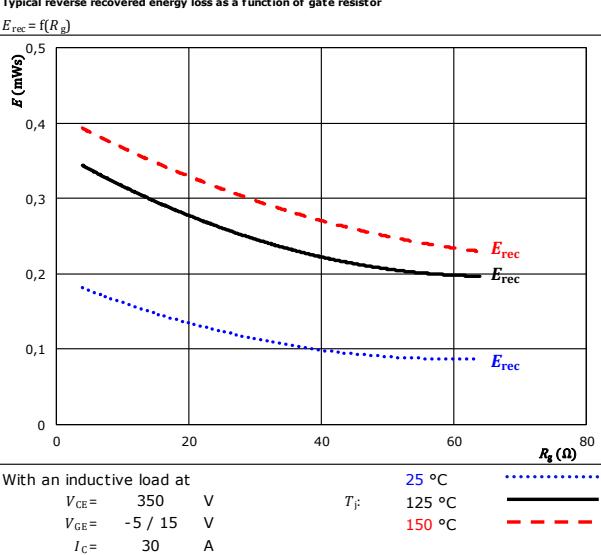


figure 4.

Typical reverse recovered energy loss as a function of gate resistor



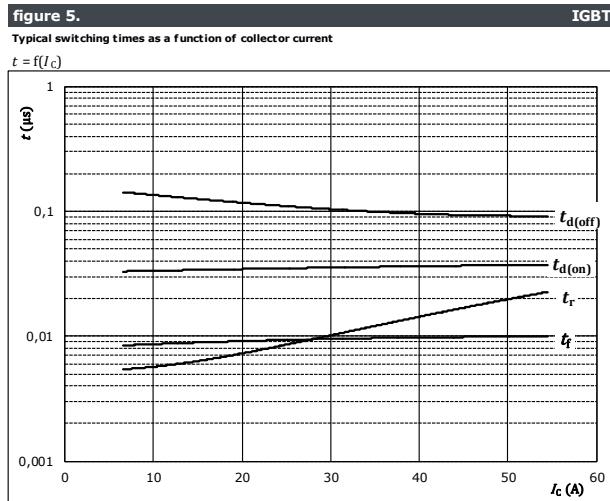


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datasheet

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H-Bridge Switching Characteristics



With an inductive load at

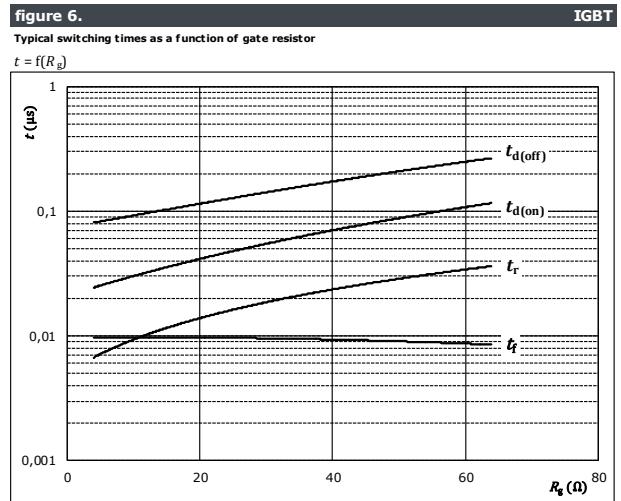
$$T_f = 150 \text{ } ^\circ\text{C}$$

$$V_{CE} = 350 \text{ V}$$

$$V_{GE} = -5 / 15 \text{ V}$$

$$R_{gon} = 16 \Omega$$

$$R_{goff} = 16 \Omega$$



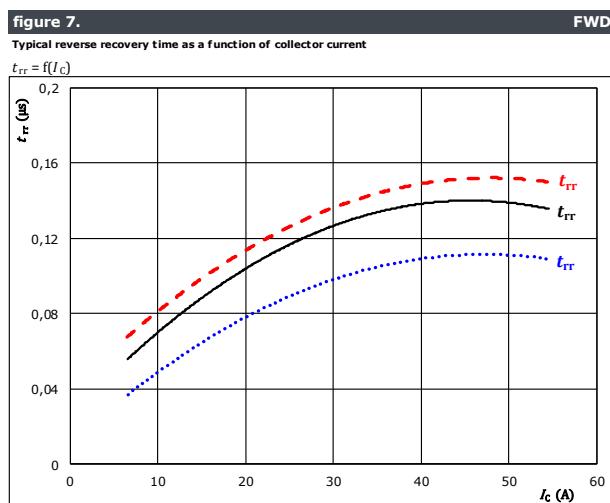
With an inductive load at

$$T_f = 150 \text{ } ^\circ\text{C}$$

$$V_{CE} = 350 \text{ V}$$

$$V_{GE} = -5 / 15 \text{ V}$$

$$I_C = 30 \text{ A}$$



With an inductive load at

$$V_{CE} = 350 \text{ V}$$

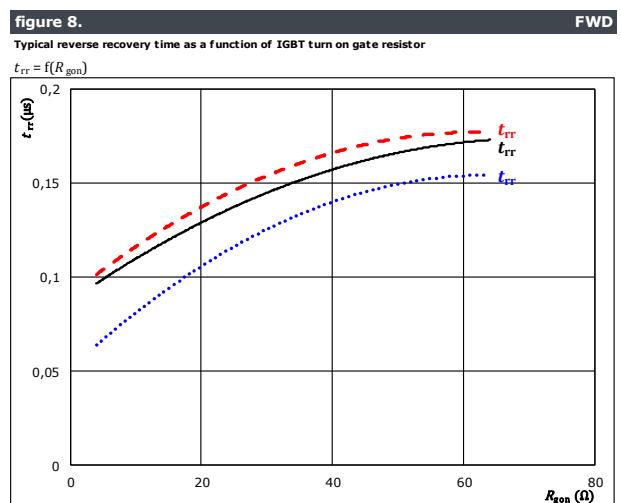
$$V_{GE} = -5 / 15 \text{ V}$$

$$R_{gon} = 16 \Omega$$

$$25 \text{ } ^\circ\text{C} \quad \cdots \cdots$$

$$T_f: 125 \text{ } ^\circ\text{C} \quad \text{---}$$

$$150 \text{ } ^\circ\text{C} \quad \text{--- ---}$$



With an inductive load at

$$V_{CE} = 350 \text{ V}$$

$$V_{GE} = -5 / 15 \text{ V}$$

$$I_C = 30 \text{ A}$$

$$25 \text{ } ^\circ\text{C} \quad \cdots \cdots$$

$$T_f: 125 \text{ } ^\circ\text{C} \quad \text{---}$$

$$150 \text{ } ^\circ\text{C} \quad \text{--- ---}$$



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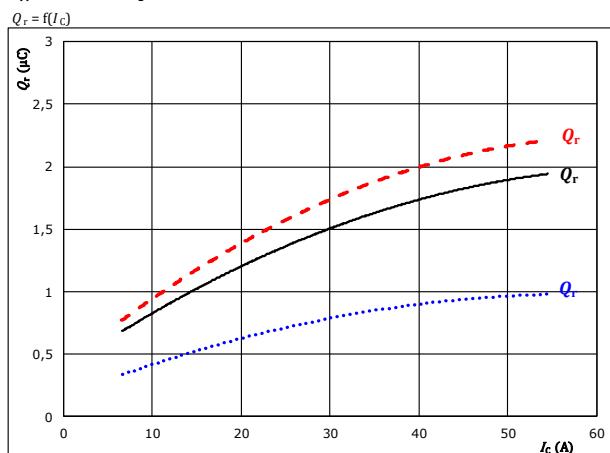
10-FY07ZAA030SM-L513B28

datasheet

H-Bridge Switching Characteristics

figure 9.

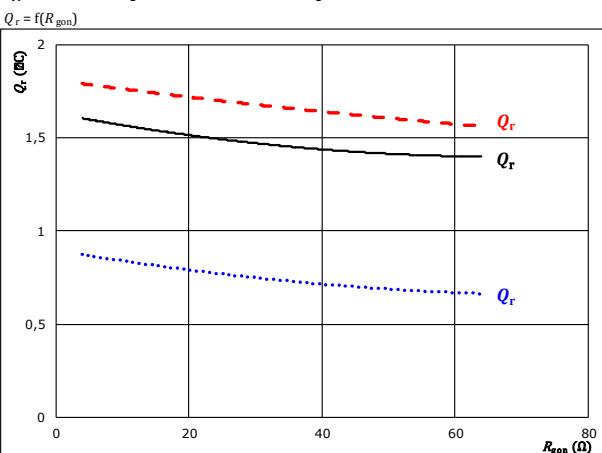
Typical recovered charge as a function of collector current



With an inductive load at
 $V_{CE} = 350$ V $T_f = 25^{\circ}\text{C}$ $Q_r = \dots$
 $V_{GE} = -5 / 15$ V $T_f = 125^{\circ}\text{C}$ $Q_r = \dots$
 $R_{gon} = 16$ Ω $T_f = 150^{\circ}\text{C}$ $Q_r = \dots$

figure 10.

Typical recovered charge as a function of IGBT turn on gate resistor

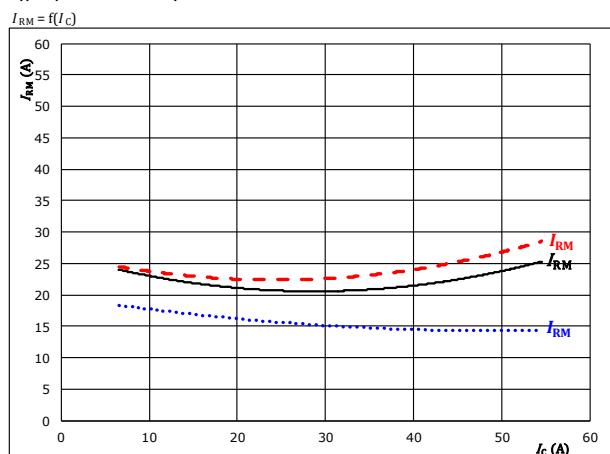


With an inductive load at
 $V_{CE} = 350$ V $T_f = 25^{\circ}\text{C}$ $Q_r = \dots$
 $V_{GE} = -5 / 15$ V $T_f = 125^{\circ}\text{C}$ $Q_r = \dots$
 $I_C = 30$ A $T_f = 150^{\circ}\text{C}$ $Q_r = \dots$

figure 11.

FWD

Typical peak reverse recovery current as a function of collector current

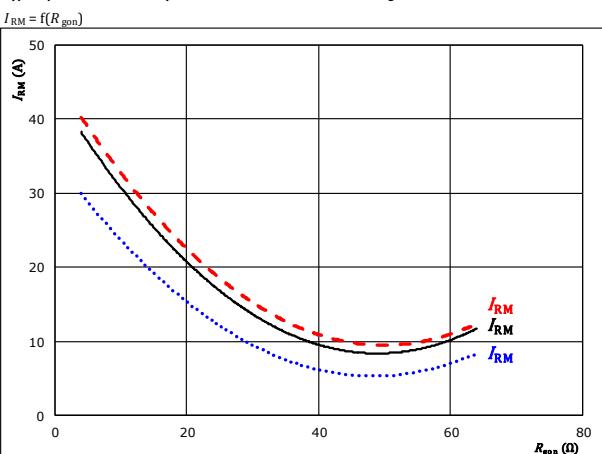


With an inductive load at
 $V_{CE} = 350$ V $T_f = 25^{\circ}\text{C}$ $I_{RM} = \dots$
 $V_{GE} = -5 / 15$ V $T_f = 125^{\circ}\text{C}$ $I_{RM} = \dots$
 $R_{gon} = 16$ Ω $T_f = 150^{\circ}\text{C}$ $I_{RM} = \dots$

figure 12.

FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor



With an inductive load at
 $V_{CE} = 350$ V $T_f = 25^{\circ}\text{C}$ $I_{RM} = \dots$
 $V_{GE} = -5 / 15$ V $T_f = 125^{\circ}\text{C}$ $I_{RM} = \dots$
 $I_C = 30$ A $T_f = 150^{\circ}\text{C}$ $I_{RM} = \dots$



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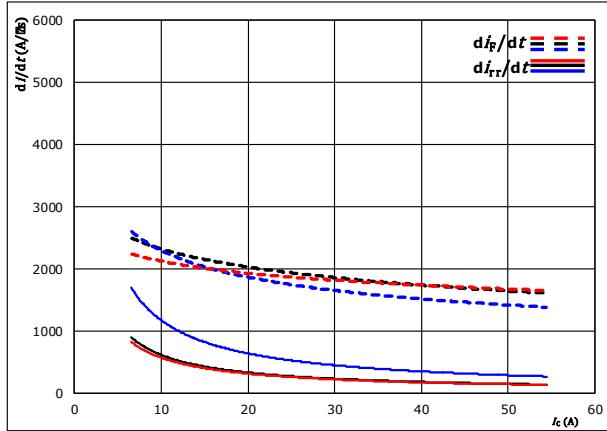
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datasheet

H-Bridge Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_F/dt, di_{rr}/dt = f(I_C)$



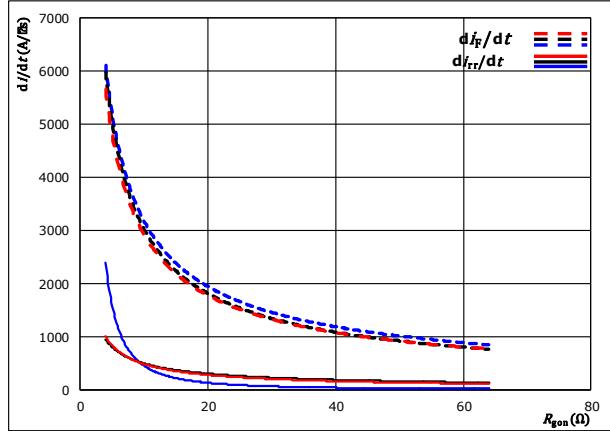
With an inductive load at

$V_{CE} = 350 \text{ V}$ $T_J = 25^\circ\text{C}$
 $V_{GE} = -5 / 15 \text{ V}$ $T_J = 125^\circ\text{C}$
 $R_{gon} = 16 \Omega$ $T_J = 150^\circ\text{C}$

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$di_F/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

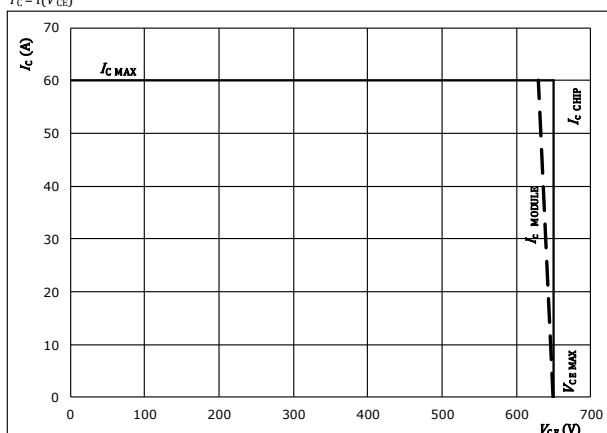
$V_{CE} = 350 \text{ V}$ $T_J = 25^\circ\text{C}$
 $V_{GE} = -5 / 15 \text{ V}$ $T_J = 125^\circ\text{C}$
 $I_C = 30 \text{ A}$ $T_J = 150^\circ\text{C}$

figure 15.

IGBT

Reverse bias safe operating area

$I_C = f(V_{CE})$



At

$T_J = 150^\circ\text{C}$
 $R_{gon} = 16 \Omega$
 $R_{goff} = 16 \Omega$



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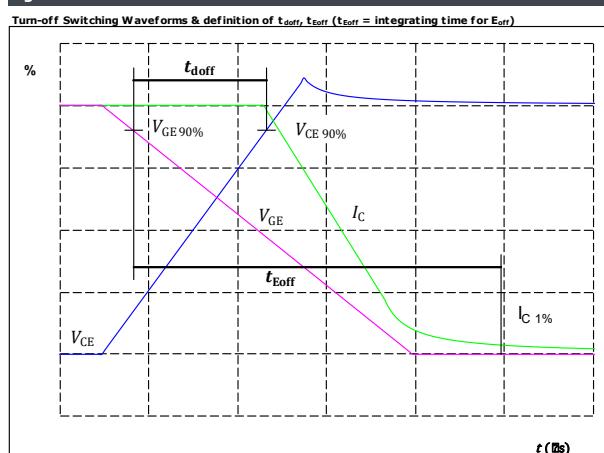
H-Bridge Switching Definitions

General conditions

T_j	=	150 °C
R_{gon}	=	16 Ω
R_{goff}	=	16 Ω

figure 1.

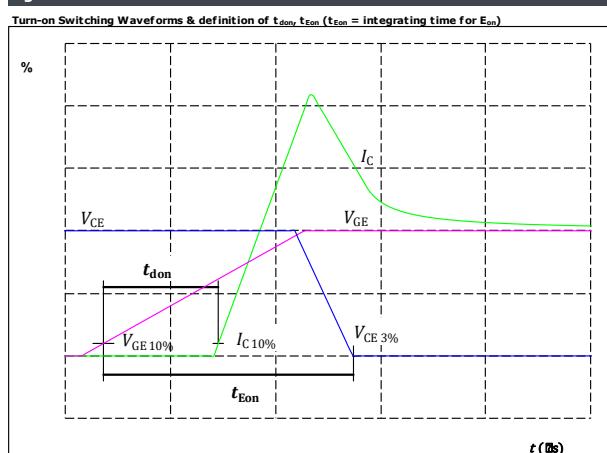
IGBT



$V_{GE\ (0\%)} = -5 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 350 \text{ V}$
 $I_C\ (100\%) = 30 \text{ A}$
 $t_{doff} = 105 \text{ ns}$

figure 2.

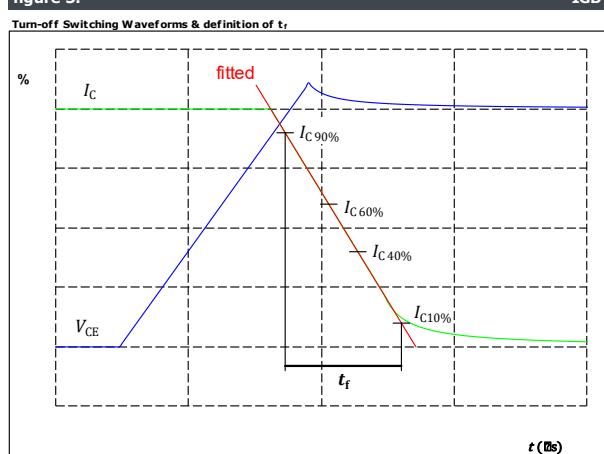
IGBT



$V_{GE\ (0\%)} = -5 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 350 \text{ V}$
 $I_C\ (100\%) = 30 \text{ A}$
 $t_{don} = 37 \text{ ns}$

figure 3.

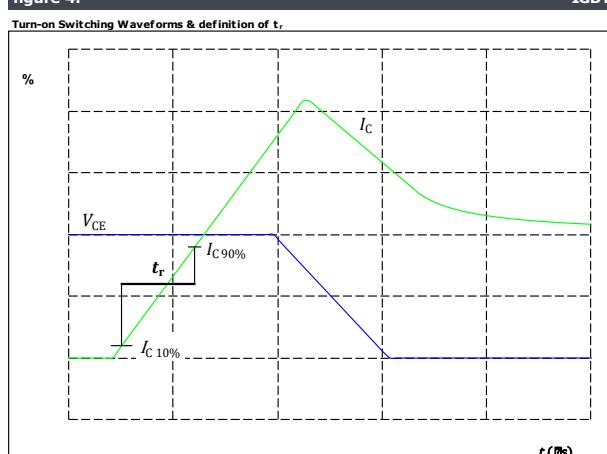
IGBT



$V_C\ (100\%) = 350 \text{ V}$
 $I_C\ (100\%) = 30 \text{ A}$
 $t_f = 10 \text{ ns}$

figure 4.

IGBT



$V_C\ (100\%) = 350 \text{ V}$
 $I_C\ (100\%) = 30 \text{ A}$
 $t_r = 10 \text{ ns}$



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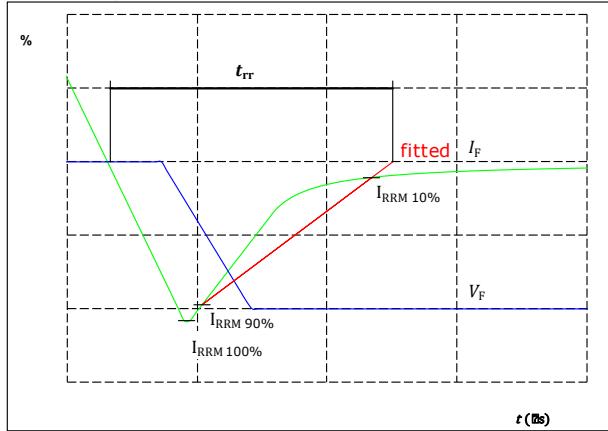
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datasheet

H-Bridge Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

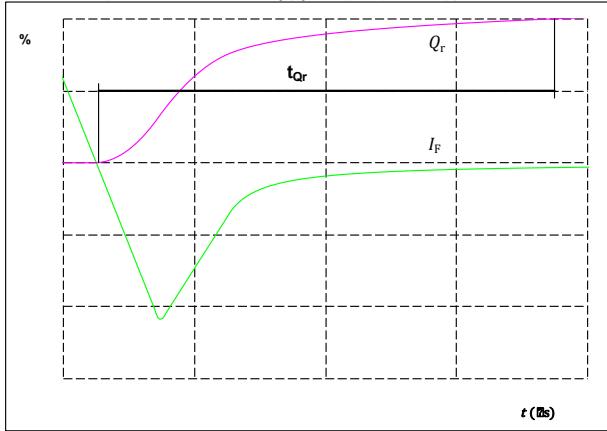


$V_F(100\%) =$	350	V
$I_F(100\%) =$	30	A
$I_{RRM}(100\%) =$	23	A
$t_{rr} =$	137	ns

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)



$I_F(100\%) =$	30	A
$Q_r(100\%) =$	2	μC



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10-FY07ZAA030SM-L513B28

datasheet

Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 12 mm housing with Solder Pins				10-FY07ZAA030SM-L513B28			
with thermal paste 12 mm housing with Solder Pins				10-FY07ZAA030SM-L513B28-/3/			
NN-NNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS			Text	Name	Date code	UL & VIN	Lot
				NN-NNNNNNNNNNNN-TTTTTVV	WWYY	UL VIN	LLLL
			Datamatrix	Type&Ver	Lot number	Serial	Date code
				TTTTTTVV	LLLLL	SSSS	WWYY

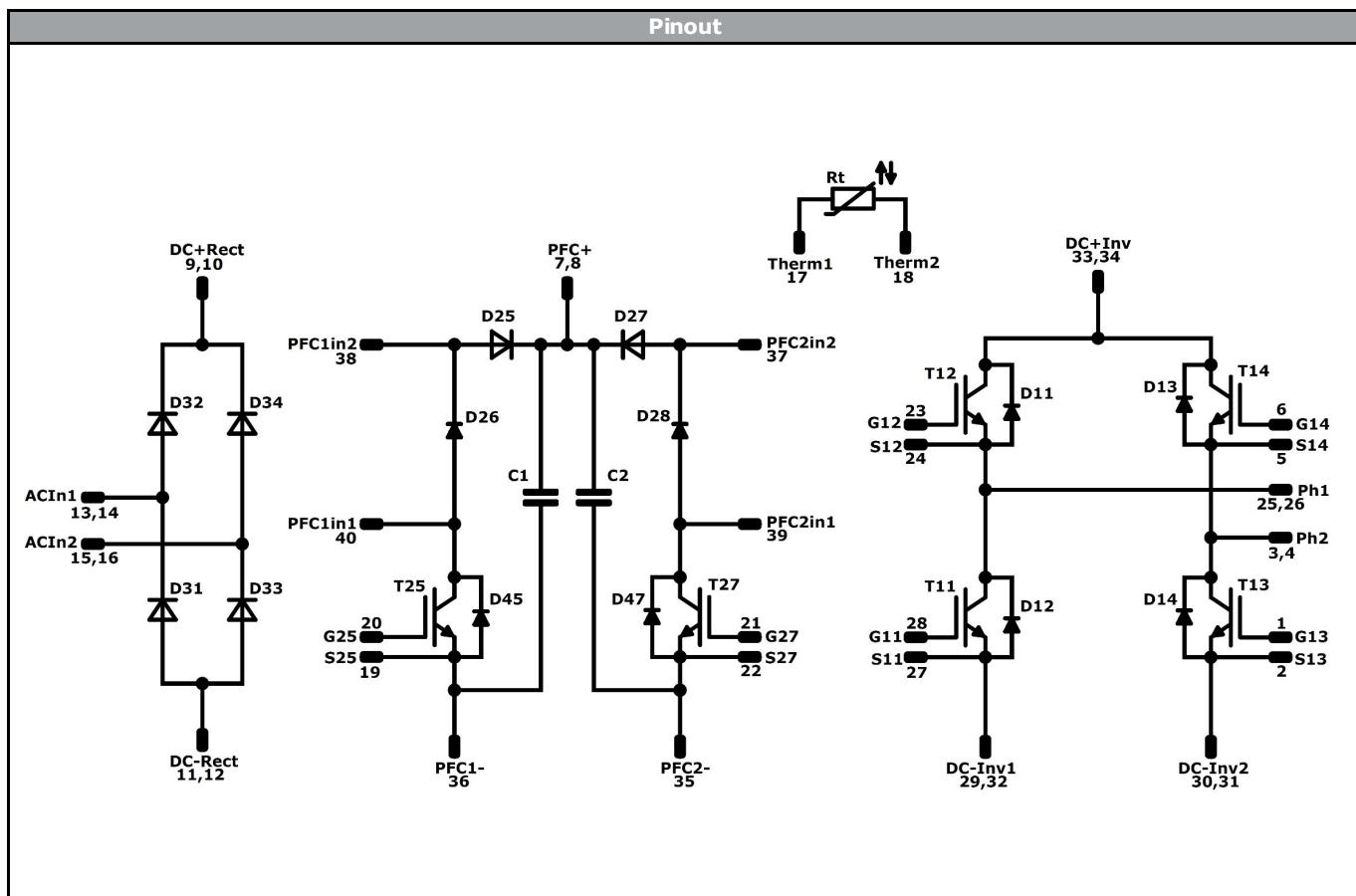
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10-FY07ZAA030SM-L513B28

datasheet

Vincotech



Identification

ID	Component	Voltage	Current	Function	Comment
D31, D32, D33, D34	Rectifier	1600 V	35 A	Rectifier Diode	
T25, T27	IGBT	650 V	20 A	PFC Switch	
D25, D27	FWD	650 V	20 A	PFC Diode	
T11, T12, T13, T14	IGBT	650 V	30 A	H-Bridge Switch	
D11, D12, D13, D14	FWD	650 V	20 A	H-Bridge Diode	
D26, D28	FWD	650 V	10 A	Current Transformer Protection Diode	
D45, D47	FWD	650 V	10 A	PFC Sw. Protection Diode	
C1, C2	Capacitor	630 V		Capacitor (DC)	
Rt	NTC			Thermistor	



10-FY07ZAA030SM-L513B28

datasheet

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Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 1 packages see vincotech.com website.			

Package data			
Package data for flow 1 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-FY07ZAA030SM-L513B28-D1-14	20 May. 2019		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.